Office européen des brevets

(12)EUROPEAN PATENT APPLICATION published in accordance with Art. 158(3) EPC

(43) Date of publication: 16.08.2000 Bulletin 2000/33

(21) Application number: 99940637.4

(22) Date of filing: 03.09,1999

(51) Int. Ct.7: H01M 4/02, H01M 4/38. H01M 10/40, B22F 9/08, B22F 9/10

(86) International application number: PCT/JP99/04775

(87) International publication number: WO 00/14817 (16.03.2000 Gazette 2000/11)

(84) Designated Contracting States: AT BE CHICY DE DK ES FI FRIGB GRIE IT LILU MC NL PT SE

(30) Priority: 08.09.1998 JP 25398198

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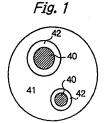
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(54)NEGATIVE ELECTRODE MATERIAL FOR NONAQUEOUS ELECTRODE SECONDARY BATTERY AND METHOD FOR PRODUCING THE SAME

A negative electrode material for a nonaqueous electrolyte secondary battery having a high discharge capacity and a good cycle life is made from alloy particles having an average particle diameter of 0.1 - 50 µm and including Si phase grains 40 and a phase of a solid solution or an intermetallic compound of Si and other element selected from Group 2A elements, transition elements, Group 3B elements, and Group 4B elements from the long form periodic table (for example, an NiSio phase 42 and an [NiSio + NiSi] phase 41) at least partially enveloping the Si phase grains, 5-99 wt% of this material is Si phase grains. The alloy particles can be manufactured by rapid solidification (such as atomization or roller quenching) of a melt including SI and the other element or by adhering the other element to Si powder by electroless plating or mechanical alloying and then performing heat treatment. Even if rapid solidification is carried out, a negative electrode material having a good discharge capacity and cycle life is obtained without heat treatment.



Description

Technical Field

5 (0001) This invention relates to a material in the form of a powder for a negative electrode for a non-aqueous electrodyte secondary battery which can reversibly couldre and release large amounts of stalks intellas usual as Li, and to manufacturing processes for the negative electrode material. This invention elso relates to a process for manufacturing a negative electrode to meter form to a non-aqueous electrodyte secondary battery unit to a non-aqueous electrodyte secondary battery unit this negative electrode material and to a non-aqueous electrodyte secondary battery unit this negative electrode material and which is improved with respect to charge and discharge capacity as well as 10 could life.

[0002] A non-equeous electrolyte secondary battery according to this present invention includes both batteries using a non-equeous electrolyte in solution of a supporting electrolyte dissolved in an organic solvent, and batteries using a solid non-equeous electrolyte in the form of a polymer electrolyte, and electrolyte, or the like.

15 Technical Background

[0003] As portable, small electric and electronic devices become more widespread and improve in performance, the production of non-aqueous electrolyte secondary batteries typified by lithium ion secondary batteries has greatly increased, and improvements in their capacity and cycle life are continuously demanded.

[0004] At present, in typical non-aqueous electrolyte secondary batteries, carbon materials are primarily used as negative electrode materials. However, in negative electrodes made from carbon materials, it is an only to eccluded up to the composition LiC_p. Therefore, the theoretical maximum limit on the capacity is 372 mAM_Q, which is only approximately 1/10 that for the case for metallic lithium, and there is a limit on increases in capacity.

[0005] Metallici lithium, which was initially used as a negative electrode material, can provide a high capacity, but 29 repeated charging and discharging of a battery cause the precipitation and growth of dendrite crystals, leading to the occurrence of short-directifing, so the cycle like of charging and discharging was short, and it was not practical.

[0006] With the object of obtaining a high capacity, it has been proposed to use the element AI, which can reversibly occlude and release Lib yith formation of an intermediatic compount, as a negative electrodro attention. However, due to changes in volume accompanying occlusion and release, the negative electrode material stort for morads which so causes powderization or communition of the metarical into a fire provider. Therefore, in secondary batteries using this negative electrode material, as cycles of charging and discharging progress, the capacity abruptly decreases, so they have a short cycle life.

(9007) As a massure to prevent this powderization of a negative electrode material caused by changes in volume, it has been proposed to add I, Si, B, or the like to A In a negative electrode material in order to increase the lattice as constant of the aluminum material in edvenoe (Japanese Published Unexamined Patent Application No. He's 3-280383). However, the effect is inadequate, and it is not possible to sufficiently increase the ovice of the proposed of the proposed

[0008] It has also been proposed to occlude and release Li within the lattice of silicides or other intermetallic compounds (Japanese Published Unexamined Patent Applications Nos. Hel 7:240201, Hel 9:63651, etc.), but in each case, a storificant Heck was not obtained.

(0009) Various types of negative electrode materials for non-aqueous electrolyte secondary batteries and negative electrodes formed from those materials have been proposed, but a negative electrode material having a structure which can best exhibit the performance of those materials and a process for its manufacture have not been proposed.

Disclosure of the Invention

[0010] An object of this invention is to provide a negative electrode material for a non-aqueous electrolyte secondrally battery which can occube and release large a mounts of Li and which therefore, when used as a negative electrode material for a non-aqueous electrolyte secondary battery, provides a high charge and discharge capacity, a small decrease in capacity during reaseable changing and obstanctine, and an excellent opole life.

50 [0011] Another object of this invention is to provide a negative electrode material having a structure which enables a non-equeous electrolyte secondary battery equipped with a negative electrode made from this negative electrode material to best exhibit its procerties and to a manufacturing process for the negative electrode.

[0012] Silicon (S) can reversibly occlude, and release Li through the formation of an intermetallic compound with Li (such as Li₂S₆). The charge and discharge capacity of Silwhen it is used in a negative electrode material for non-sea aqueous electrolyte ascondary batteries is theoretically a high value of approximately 4020 m/bh/g (8900 m/bh/c: specific gravity of 223). This theoretical maximum capacity is far larger than the theoretical maximum capacity of 372 m/bh/c: specific gravity of 227 of carbon materials which are actually used at present, and even compared with the theoretical maximum capacity of 3000 m/bh/c (2100 m/bh/c: specific gravity of 0.53) for materials lithium.

it has a far larger electrode capacity per unit volume, which is important from the standpoint of reducing the size of batteries. Accordingly, Si can be used as a high capacity negative electrode material.

[0013] However, as is the case with A₄ a negative electrod material made from SI metal easily turns to fine powder due to cracks formed by changes in volume accompanying coducion and release of U, so its capacity greatly decreases as charging and discharging opies continue, and its cycle life is short. Therefore, up to the present, there have been almost no attention time SI as a need the electrode matterial.

[0014] The present inventors noticed the high theoretical capacity of a negative electrode material made from St. As a result of investigations aimed at increasing the cycle life thereot, they found that if the surface of St phase grains is enveloped in a phase of an St-containing solid solution or intermetalic compound, changes in volume accompanying 10 cocclusion and discharge of Li are restanded, so cracking and powder/tastion of St can be prevented, and the cycle is increased, in order to sufficiently obtain this effect so that the restraint by the solid solution or intermetallic compound used for enveloping will be effective, the St phase preferably has a small grain size. Such small St phase grains can be efficiently formed by a rapid (configure) solidification method.

[0015] The present invention provides a negative electrode material for a non-aqueous electrolyte secondary battery, which is made from alloy particles of a structure comprising one or more SI phase grains and a phase of an Sicontaining solid solution or intermetatic compound which at least partially envelops the SI phase grains, wherein the average particle diameter of the alloy particles is at least 0.1 µm and at most 50 µm, and the SI phase grains constitutes at least 5 W/S, and at most 99 w/S of the negative electrode material.

[0016] The "Si-containing solid solution or intermetallic compound" which envelops the Si phase grains in the alloy particles can be constituted by SI and at least one element selected from the group consisting of Group 2A elements,

transition elements, Group 3B elements, and Group 4B elements other than SI of the long form periodic table.

[0017] The negative electrode material for a non-aqueous electrolyte secondary battery can be manufactured by the processes described below.

[0018] One process comprises a step of cooling a melt of raw materials for forming alloy particles (elemental SI+s at least one element capable of forming a gold soldution or an intermediatic compound with SI) for solidification so as to obtain a cooling rate of at least 100°C per second, thereby forming an alloy comprising SI phase grains and a phase of an Si-containing solid solution or intermediatic compound which at least partially envelops the SI phase grains in the process may further include a step of subjecting the alloy obtained in the solidification step to heat treatment at term-parture at least 10°C below the solidate step to subjecting the solid solution or the intermetatic compound. The purpose of this heat treatment is to remove stains which develow within the alloy due to the ratio solidification. It can be carried.

of this heat treatment is to remove strains which develop within the alloy due to the rapid solidrication. It can be carried out when the schart of strains is large. The cooling of the melt at a cooling rate of all east 100°C per second can be carried out by a method selected from the group consisting of the atomization method, the roller quenching method, and the rotatine selected sembled.

[0019] Another manufacturing process comprises a step of forming an adhering layer of a material which contains an element capable of forming a cold doution or an intermetalic compound with St. on the surface of a prowder of metallic St or an alloy having an St phase, and a step of subjecting the powder having the adhering layer to heat frestment at a temperature at least 10°C below the solidus temperature or the solid solution or the intermetalic compound to convert the material forming the adhering layer into an Si-containing solid solution or intermetalic compound. The adhering layer can be formed by a platian method or a mechanical allowing method.

40 [0020] In either of the above-described manufacturing processes, it is preferable that the alloy particles which are formed contain on the average at least 5 wt% and at most 99 wt% of Si phase grains, and that the average particle climater of the alloy particles at least 0.1 µm and at most 50 µm.
[0021] According to this invention, a manufacturing process for negative electrodes for non-aqueous electrolyte

secondary batteries is also provided. This process is characterized in that a powder of metallic SI or of an alloy containing an SI phase is adhered along a negative electrical subtrate to form a powder layer on the substrate, hereafter a material comprising an element capable of forming a solid solution or an intermetallic compound with SI is plated on the powder layer, and then heat treatment is performed at a temperature at leasts 10°C blood whe solidus temperature of the solid solution or intermetallic compound such that the plating is convent into an Si-containing solid solution or intermetallic compounds.

50 [0022] The present invention also relates to a non-aqueous electrolyte secondary battery equipped with a non-aqueous electrolyte and positive and negative electrodes which can evereitely occube and release electrode related in that the negative electrode contains the above-described negative electrode material, and the control of the present electrode material amunificative electrode material, or it is a negative electrode material.

10023] The negative electrode may contain at least 5 w% and at most 80 wt% of a carbon material with respect to the above-described negative electrode material. The positive electrode preferably comprises a lithium-containing transition metal compound as an active material, and the non-acqueup electrolyte is preferably a solution of a lithium still.

dissolved in an organic solvent containing a carbonate ester.

Brief Description of the Drawings

[0024]

Figure 1 is an explanatory view showing one example of a structure of alloy particles according to this invention. Figure 2 is a cross-sectional view showing the structure of a non-aqueous electrolyte secondary battery which was prepared as a test battery for an example.

Description of Modes of the Invention

[0025] Below, a negative electrode material according to the present invertion and processes for its manufacture, a process for manufacturing a negative electrode made from this negative electrode material, and a non-equeque electrolyte secondary battery utilizing this negative electrode material will be described in detail. In the following explanation, unless otherwise indicated, all the percents relating to material compositions refer to percent by weight (wt%).

Negative Electrode Material

- [0025] A negative electrode material according to this invention is made from alloy particles of a structure comprising one or more Si phase grains as a core, and a phase of an Si-containing solid solution or intermetallic compound which at least partially envelopes the Si phase gains (referred to below as an enveloping material). The enveloping material may be a mixture of an Si-containing solid solution and intermetallic compound, and it may further include other chasses.
- 25 [0027] The Si phase grains forming the core are an active substance for a negative electricide. By forming an intermetallic compound with LI (such as Li₂₂Si₂), they can reversibly combine with and dissociate from littinum, hamely, at the time of changing, they combine with LI to occlude LI, and at the time of discharging, they diseaseous from LI to release LI. The Si phase grains may include other phases dispersed therein provided that the Si phase is a matrix of the orarins.
- 30 [0028] The phase of an Si-containing solid solution or intermetallic compound which is the enveloping material restrains changes in Journe of the SI phase accompanying occlusion and release of Li and it supersesses tracking and powderization thereof, thereby increasing the cycle life. Event if the SI phase grains which are the negative electrode active material are completely enveloped by the enveloping material, since Li lone have an extremely small ion radius, they can easily pass through the lattice of the enveloping material to reach the SI phase core and can combine therewith. In the same manner, Li Ions which have diseassociated from the SI phase can pass through the enveloping material and be released into the electrolyte solution. Namely, the enveloping material can restrain volume changes of the SI phase can pass through the enveloping material can restrain volume changes of the SI phase can pass through the enveloping material.
- [0029] The object of enveloping is to restrain volume changes of the SI phase grains which are the active material of negative electrodes. Theoretically, a material which does not contain SI may be used as the enveloping material.

 40 However, if the enveloping material is deached from the core, it can not achieve its objective. In order to prevent this detachment, the enveloping material is made of a phase of an S-cortaining solid colution or intermettallic compound which solidifies at the same time as the SI phase or which can be formed by the diffusion of SI from SI element in the core which it envelopes.
- [0030] The enveloping material may completely envelop the core of Si phase grains or may partially envelop it.
 6 Even in the case in which it partially envelops it, the above-described objective or restraint can be substantially achieved. Particularly in inclustrial production, it is difficult to completely envelop all of the Si phase grains in the strict sense of the word, and it is also difficult to acceptant whether complete envelopment has taken place.
- [0031] The individual alloy particles which make up the powdery negative electrode material may contain a single sighese grains. In the case in which it contains a single Si phase grain as elloyparticle so is a particle in which the periphery of this single Si phase grain is at least partially enveloped by the enveloping material. When an alloy particle includes a plurality of Si phase grains, trybcally the Si phase grains are dispersed within the matrix of the enveloping material (the Si phase grains are relatively minute, and the proportion of the enveloping material in the simple size of the size
 - [0032] The average diameter of the Si phase grains in the alloy particles is preferably at least 0.01 µm and at most 40 µm, and more preferably it is at least 1 µm and at most 35 µm. If the average diameter of the Si phase grains forming

the core exceeds 40 µm, It may be difficult for the above-described restraint to work effectively, or the average particle diameter of the sloty particles may exceed 50 µm, thereby making it difficult to prevent powderization of \$3 and deterioration in cycle life. If the average diameter of the Si phase grains is less than 0.01 µm, surface oxidation and the like of the alloy particles at the time of manufacture can easily take place, and handling becomes difficult. In the case in which an alloy particle contains a plurality of \$1 phase gains, the average diameter of the \$1 phase gains is preferably at most 20 µm.

[0033] The everage particle diameter of the alloy particles is at least 0.1 μm and at most 50 μm. If the everage particle diameter of the alloy particles exceeds 50 μm, the packing density of the negative electrode material in electrodes become small and the capacity thereof decreases. Furthermore, as described above, the average particle of the everage particle diameter covered 50 μm, the thickness of the enveloping material becomes to great, the proportion represented by the 50 phase decreases, and as a result the capacity of the negative electrode material becomes small. If the average particle diameter of the alloy particles is smaller than 0.1 μm, the enveloping material becomes to thin, and it becomes difficult for the above-described restraint to work effectively. The average particle diameter of the alloy particles is preferably at least 1 μm and at most 40 μm, and more overlands the least 5 μm and at most 40 μm, and more

[0034] For both the Si phase grains and the alloy particles, when the particle stape is irregular (non-spherical), such as flake shaped (thin pieces), the particle diameter of an alloy particle is the average of its minor axis and its major axis. The average value with respect to particle volume of the particle diameter of the alloy particles determined in this manner is taken as the average particle diameter.

1035] The diameter of the Si phase grains can be measured by a scanning electron microscope (SEM), for example, Various methods can be used to measure the particle diameter of the alloy particles, For example, the median diameter of the volume particle distribution measured with a laser diffraction particle size measuring apparatus can be taken as the everage particle diameter, and this method is used in the examples.

[0036] The Si phase grains constitute 5 to 99 wt% of the negative electrical material. Prailerably, the remainder is comprised secentially of a phase of an Si-conditing solid solution or intermetablic compound (name), the alloy particles consists essentially of this phase and Si phase grains). However, if there is no extreme adverse effect on negative electrode properties, a third phase not containing Si may be present in the alloy particles. If the proportion of the Si phase exceeds 99 wt%, the thickness of the envelocing material becomes too small, and it becomes (finduit for the envelocing material becomes too small, and it becomes (finduit for the envelocing material becomes too small, and it becomes (finduit for the envelocing material becomes too small, and it becomes (finduit for the envelocing material becomes too small, and it becomes the section of the Si phase is less than Si will, will give so an engative electrode material having a too small capacity. The proportion of the Si phase is preferably at least 8 wt%, and at most 5 wt%, and more orderably at least 10 wt%, and at most 50 wt%.

[0037] As stated above, the material forming the enveloping material comprises an S-containing solid solution or intermetallic compound in order to prevent detachment of the material from the core of SI phase grains. Elements for forming the Si-containing solid solution or informatallic compound are preferably one or more metal elements selected from the group consisting of Group 2A elements (alkali earl'n metals), transition elements, Group 3B (boron group) elements, and Group 4B (cathon outcoul elements other than SI in the lone form aniotic time.)

[0038] Peterred examples of the above elements are the Group ZA elements Mg, Ca, and Ba; the transition elements Mg, Pc, ca, and cher rare earth elements, and T. Cr, W. Mn, Fc, Co, Ni, and Cut, the Group 38 elements Al, Ca, and T, and TT, and the Group 4B elements Ge, Sn, and Pb. Of these, more preferred elements are Mg, Ca, W, Fe, Co, and Ni.

Manufacturing Process for a Negative Electrode Material

[0039] A negative slockrod material for a non-equeues electrolyte secondary battery according to the present of invention margine formal lay particles having a structure in with on one more Siphase grains are at least partially enveloped in an enveloping material of an Sicontiatining solid solution or intermetallic compound can be manufactured by either of the two manufacturing processes within with be now described.

[Manufacturing Process 1]

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[0040] A malt which is obtained by matting raw materials for forming alloy particles (namely, a mixture of Si and one or more elements which can from a places of a solid solution or intermetalic compound with Si) is cooled so as to obtain a solidification speed (cooling rate during solidification) of at least 100°C per second to solidify it, whereby an alloy in which Si phase grains are at least spartially enveloped in an Si-containing solid solution or intermetallic compound is so from the Independent or intermetallic compound is solid to solid to return the solid section or intermetallic solid solid containing solid solid containing solid solid containing solid solid containing solid solid contained in compound is solid solid contained solid contained in compound to subject the Si-containing solid solidion or intermetallic compound forming the enveloping material, and/or't can be subjected to grinding. When heat treatment is carried out, grinding may be performed either before or after heat treatment.

[0041] In this first process, as a result of solidification of the above-described melt, an alloy is formed in with of St phase grains are at least partially enveloped in an St containing soil student or intermetalis compound. By performing rapid cooling os as to obtain a cooling rate of at least 100°C per second to perform solidification, many nuclei for precipitation are formed. Therefore, in the case of a multiphase alloy, the phase of the primary crystal which first precipitates and the phases which precipitate after that become minute. Namely, in the case of the above-described alloy, both this St phase and the phase of the primary control which have fine or an instruction.

[0042] The alloy structure formed by precipitation of various phases during solidification greatly varies with the alloy composition. In the case in which the alloying raw materials have a composition corresponding to an euclectic alloy, the Si phase and the phase of an Si-containing solid solution or intermetallic compound precipitates simultaneously, and an alloy structure is obtained in which the SI phase and the phase of an Si-containing solid solution or intermetallic compound are finely mixed. In the case in which the SI phase is a primary crystal, an alloy is obtained with a structure in which the firm SI phase grains which precipitate first are at least partially enveloped in the fine phase of an Si-containing solid solution or intermetallic compound is not primary crystal. As a presult, he precipitate are cases this phase is eutlective with the SI phase) within precipitates from the phase of an Si-containing solid solution or intermetallic compound is the primary crystal. As a result, an alloy is obtained having a structure in which the SI phase grains are dispersed in the phase of an Si-containing solid solution or intermetallic compound. Either alloy structure can be said to be an alloy in which fire SI phase grains are at least partially enveloped in a phase of an Si-containing solid solution or intermetallic compound.

p[00.43] The motion raw materials should be rich in Si compared to the composition of the Si-containing solid solution or intermedialic compound phase which becomes the enveloping material Depending on the proportion of SI to other elements in the raw materials, the proportion of the negative electrode material constituted by the SI phase grains formed during solidification is determined. Alloy particles which are manufactured by Process that possibly include a single SI phase grains. This process has relatively simple manufacture grains. This process has relatively simple manufactured.

5 facturing steps

[0044] If the cooling rate is less than 100°C per second, the Si phase grains which precipitate grow and become too coarse, and the average diameter thereof may exceed duy. The cooling rate is pretarbly at least 1000°C per second. The upper limit on the cooling rate is not restricted, but industrially it is preferably at most on the level of 10°°C per second.

39 [0045] As cooling methods for achieving a cooling rate of at least 100°C per second (relarred to below as rapid solidification methods), atomization, roller quenching, and rollating electrod methods are preferable, lading into consideration the completeness of menufacturing technology, suitability for mass production, costs, and the like. Of these methods, along the control endough control of the complete of the control of the cont

[0046] For atomization, either of gas atomization and fauld atomization is possible, but gas atomization which results in the formation of nearly specified particles in preferred in either case, in corder to prevent oxidation of the alloy, the meting and solidification environment are preferably maintained in a non-oxidizing atmosphere (for example, in a vincum or an inter das atmosphere).

[0047] In gas atomization, altoying raw materials having a prescribed composition are normally melled in a vacuum or an inert atmosphere in a light frequency induction melting furnace. The motien alloy (mell) which is formed is 40 ctopped into an atomizing tank through a mell supply pipe. A nozzle is installed near the mell supply pipe, and an atomizing gas is blown out from a hold or sidt of the nozzle at the dropping mell. The mell is castered by the discharged gas into droplets, which rapidly solidifies to form a powder. The powdery alloy which is formed is led to a powder storing apparatus from the bottom of the abmizition tank and is stored therein?

[0048] The particle diameter of the powder which is formed by gas atomization normally becomes smaller as the energy of the gas which is blown at the dripping mell increases. The energy of the blown gas can be adjusted by, for example, the pressure of the gas and the size or position of the hole or slit in the nozzle. For blown gas having the same energy, the particle diameter of the powder normally becomes smaller as the amount of dropped mell per unit time decreases. The amount of dropped mell can be adjusted by the inner diameter of the mell supply pipe and the pressure applied to the mell within the mell supply pipe.

20099] Roller quenching is a method in which a met tof an alloying raw material having a prescribed composition is poured in a finit layer out he outer periphery of a cooled rading roll whereby the heat of the poured meth is withdrawn rapidly by the cooled roll to effect rapid cooling. Both a single roll and twin rolls can be used. The meth is normally housed in a tundfs, and a controlled amount is poured from a nozel in the bottom thereof. The cooling rate of an alloy using roller quenching can be controlled based on the rotational speed of the roll, the amount of met which is poured, and the like.

[0050] In the case of single-roller quenching, the rotational speed of the roll is typically such that the peripheral speed at the outer periphery is in the range of 1x10² to 5x10² meters per second. A roll having a diameter of 100 - 600 mm is relatively frequently used. From the standpoint of practicality, the roll diameter is preferably 400 - 600 mm, and

the roll peripheral speed is preferably 6 x 10°2 - 1.3 x 10°2 meters per second.

[0051] The alloy which is rapidly cooled and solidified by the roll normally has the shape of foils and/or flakes, which drop off from the roll and are recovered by a suitable storage apparatus. The alloy which is obtained is generally extremely thin, so it can be easily ground into a powder by a mechanical grinding means (such as a ball mill, a jet mill, or the like). Both the prinding and roller quenching are preferably carried out in an inert gas atmosphere.

[0052] The rotating electrode method is a method in which an alloy having a prescribed composition is cast to form an electrode, and while the electrode is rotated at a high speed within a closed chamber at a reduced pressure, it is successively meter starting from the tip by an art from a counter electrode, whereby the resulting meth is scattered and rapidly cooled and solidified within the chamber to form a powder. There are also variations on this method in which the mething is carried out with a plasma are or a laser. The counter electrode is normally made of turgation. The electrode is frequently cylindrical with a claimeter of 30 to 50 mm, but ones with a larger diameter also exist. The rotational speed of the electrode is normally on the order of 1000 - 5000 rpm, but there are cases in which a higher rotational speed is employed.

[00:33] In the case of an Si alloy having a high melting temporature, a plasma are cotating electrode method in which the altoy electrode is metted with a plasma arc is preferred. Are rife is frequently used as a plasma are gas. The particle diameter of the powder is determined primarily by the totational speed and diameter of the electrode. The particle diameter of the powder decreases as the rotational speed of the electrode is increased or the electrode diameter is decreased. A suitable cooling means is provided on the counter electrode or the chamber.

20034] An alloy which is formed by rapid solidification according to the first process, taking an N-Ss alloy as an poweriple, is one in which is phase grains coexist with an NSi₂ phase and at NSi phase, which are intermetablic compounds. In this example, among the three phases, the Si phase, which has the highest solidification temperature, precipitates first during solidification and forms primary crystals, and then in the periphery of the primary crystals of Si phase, NSi₂ crystallizes out are to a reaction between the liquid phase and the Si phase. Finally, the remaining liquid phase crystallizes out as autectic crystals of NSi and NSi₃, to completely solidify. As shown in Figure 4, spherical alloy particles which are formed by solidification by gas atomization or rotating electrode method have a solidified structure having Si phase gains 40 which are enveloped by an NSi₂ phase 42. The NSi₂-enveloped Si phase gains are dispersed within a matrix of a (NSi₂ + NSi₃) eutectic phase 41. These alloy particles frequently have a structure in which a plurality of Shase gains are present in a single alloy particle.

[9055] In rapid solidication, each of the phases which procipitates is minute, so the Si phase grains in the alloy owhich is formed have an average diameter which is normally at most 25 µm, and particularly with atomization or roller quenching which have a higher coding rate, the average diameter is frequently at most 10 µm. Depending on the composition of the alloy, only one type or two or more types of Si-containing intermetalic compound may precipitate together with the Si phase. With some alloying elements, an Si-containing solid solution may be formed during solidification in place of or in addition to an intermetalic compound. In either case, the phase having the lowest solidification.

3s temperature normally becomes a fine grain matrix, in which Si phase grains are present.
[0056] The alloy which is formed by rapid solidification is subjected to grinding, if necessary, and alloy particles having an average particle diameter of at least 0.1 µm and at most 50 µm are obtained. Even with attornization or rotating electrode method which provide an alloy in the form of a powder, the resulting alloy powder may be subjected to grinding as necessary or required, forfinding can be carried out by a ball mill or other conventional means.

40 [0057] Altoy particles which are manufactured utilizing a rapid solidification method sometimes have strains remaining therein due to the rapid cooling. A material flaving startis starts to cause powderstand outing use, leading to a short cycle life. Accordingly, the alloy particles may be heat treated to remove strains due to rapid cooling. In the case in which grinding is carried out, heat treatment may be carried out dethies before grainfloring or after grinding. In order to prevent oxidation of the negative electrode material during heat treatment, heat treatment is preferably carried out m a non-oxidizinal amproachers such as a vacuum or an inert use atmosphere.

[0058] Heat treatment is carried out at a temperature at least 10°C below the solidus temperature of the Si-containing intermetablic compound or solid solution forming the enveloping material. As shown in Figure 4, a temperature at least 10°C below the solidus emperature of the primary phase of the Si-containing intermetallic compound or solid solution present in the larger amount can so be used (the primary phase can be determined from the composition or from a phase diagram in the case of Figure 4, it is the NiSi, phase). A preferred heat treatment theregrature is at least 20°C below the solidus semperature.

(0099) In addition to removing stains due to rapid cooling, the heat treatment produces diffusion. According to the observations of the present inventors, the state of change of each phase when the alloy shown in Figure 4 was subjected to heat treatment was as follows.

5 (0060) In the initial stage of heat treatment, NSi within the matrix 41 made up of the (NISI₂ + NiSi) phase was suppired Si from the NiSi₂-phase 42 surrounding the particulate Si phase 40 and was converted into NiSi₂. On the other hand, the NiSi₂ phase 42 took in the Si in which it was deficient due to this supplying from the adjoining Si phase 40. As a result, the Si phase 40 contracted having a reduced average orain diameter. After all the NiSi in the (NIS) + NiSi)

phase 41 was converted to NiSl₂, the alloy particles became an alloy made up of two phases, i.e., of the NiSl₂ phase forming the matrix and the dispersed Si phase grains 40. If heat treatment is further continued, due to Ostwald growth whereby relatively large Si phase grains white relatively small Si phase grains disappear, the average diameter of the Si phase grain increases. There is no substantial chance in the average particle diameter of the alloy particles.

5 00611 Heat treatment is preleably carried out under such conditions that the average diameter of the Si phase grains 40 after heat treatment cone or exceed 40 m.f. If the heat treatment temperature is higher than 10°C below the solicus temperature, the diameter of the Si phase grains forming the core becomes too big, and depending upon the accuracy of temperature control of the heat treatment furnized which is used, the solicus temperature may end up being exceeded, sittering of the powder may take place, and subsequent grinding becomes necessary, so higher temperature is are not appropriate. The lower limit on the heat treatment temperature is not restricted so long as strains caused by rapid cooling can be removed, but it is preferably at least 500°C. The duration of heat treatment is at least two hours, taking into consideration the diffusion speed of the elements making up the alloy particles, and at least 4 hours or particularly representable.

[0062] Heat treatment normally causes the average diameter of the Si phase grains to increase and the weight perto centage thereof to decrease. This is because Si in the Si phase is consumed by the above-described conversion of NISI to NIS₂, As a result of a decrease in the weight percentage of the Si phase which is the negative electrode active material, heat treatment dives a tendency for the charge and discharge capacity to decrease.

[D063] When a negative electrode material according to the present invention is manufactured by rapid solidification, admixaction or roller quenting which have a higher cooling rate results in the formation of an alloy structure having 20 Si phases which are finely dispersed due to rapid cooling. Therefore, even if strains remain to a certain extent in the solidified alloy, it was escentianed that a negative electrode material having a good cycle file is obtained without heat treatment. Accordingly, using a process with high productivity in which a time-consuming heat treatment process is emitted, a neadlew electrode material having negative inverse deposity and good cycle file can be manufactured.

25 [Manufacturing Process 2]

[0064] On the surface of a powder of metallic Si or an alloy containing an Si phase (referred to below as an Si phase powder), an adhering layer is formed of a material including an element which can form a solid solution or intermetallic compound with Si, and then healt reatment is performed at a temperature at least 10°C below the solidies temperature or of the solid solution or intermetallic compound. Namely, this is a process in which a core of Si phase grains is formed in advance, and an envelocion material surrounding it is then formed utilizing adhesion and thermal diffusion.

[0065] In this second process, heat treatment is used to diffuse the SI which is present within the SI phase powder into the achiering layer, whereby the material forming the achiering layer is converted into an Si-containing solid solution or intermetallic compound, and alloy particles are formed in which the core of Si phase grains is at least partially enveloped by the Si-containing solid solution or intermetallic compound. Such particles are also included in the "alloy" particles of the present invention. In the case in which the prouder is made of metallic SI, the altoy particles may often include a single Si phase or rain.

[0066] The Si phase powder may be a powder of metallic Si, but it may be a powder of an Si alloy as long as Si phase has been precipitated therein. Although not limited thereto, an example of such an alloy is an Ni-Si alloy.

600577 The Si phase powder preferably has a shape without sharp corners, and it also preferably has a spherical shape in which the ratio of its major axis diameter to its minor axis diameter is at most 3. If the powder has sharp corners, it is difficult for the adhering layer to be formed uniformly. If the shape is spherical, it becomes difficult for powder-ization to take place, and the shape is also advantageous in that it becomes easy to make the thickness of the adhering layer uniform. This Si phase powder may be manufactured by a mechanical grinding method, but it is advantageous to semanticuture by the production of the produ

[0068] Whatever method is used to manufacture it, the Si phase powder preferably has an average particle diameter of at most 40 µm. If the average particle diameter of the powder exceeds 40 µm, the Si phase grains forming the core become large, it becomes difficult for the intermetallic compound formed thereon to bind effectively the core and or prevent powderization upon the occlusion and release of U.

[0699] It is not necessary for the Siphase powder to be made of single particles. Complex particles in which a plurality of particles are joined together, such as by sintering, may also be used. In the case of fine powder having a particle dameter of at most 10 µm, if the adhering layer is formed on the surface thereof in that state, the proportion of the elements in the adhering layer with respect to the weight of the powder becomes high, which is not desirable. In such a case, the fine powder can be partially sintered to form complex particles as as to decrease the proportion of the elements in the adhering layer with respect to the adhering powder. The average particle diameter of the complex particles is or before the amount of the elements.

[0070] On the surface of the Si phase powder, a material including one or more elements which can form an inter-

metallic compound or sold solution with Si (referred to below as a second element) is deposited or adhered to form an adhering layer. The adhering layer may contain Si in addition to the second element and it may contain an element other than one which can form an intermetallic compound or sold solution with Si, if present in a small amount. The second element can be adhered by either a chemical method such as plating or a physical method such as mechanical alloying fMA method.

[0071] The thickness of the adhering layer made from the second element is preferably on the order of 0.05 - 1.0 m. If it is is set ban 0.05 m, the thickness of the enveloping naterial formed from the adhering layer (the S-icontaining intermetallic compound or solid solution) becomes small, it becomes difficult for restraint of volume changes occurring with occlusion and release of 110 work effectively, and the cycle life of the electrode decreases. If the thickness of the 10 adhering layer exceeds 10 µm, the amount of the Si phase grain which is the negative electrode active material becomes relatively small, and the absolute of the negative electrode occurrence.

[0072] Armon methods for forming the achieving layer, plating method can be performed by electrolytic plating, but it involves passing a current through all of the powder which requires a complex procedure. Therefore electroless plating is more convenient. Examples of the second element which can be deposited by electroless plating include Ni, Co, 16 Pd, Qu, Ag, Au, Pt, Pb, Rh, and Ru. When the surface of the SI phase powder is covered with an oxide film or the like which interferes with plating, the oxide film can be enrowed by appropriate means such as pricting for the electroless plating, it is also effective to use a metal plating assistant such as Pd or Sn to increase the adhesion of the electroless plating.

[0073] In the case in which the second element forming the adhering layer is an element which is difficult to plate, the second element can be adhered to the Si phase powder by the Ah method. Is a method in which the Si phase powder and a powder of the second element (which can be manufactured by the same method as for the Si phase powder) are together charged into a high energy mill such as a planetary ball mill or a disintegrator-type mill and mixed together, resulting in affection of the powder of the second element to the surface of the Si alloy powder.

(D074) The average particle diameter or the powder of the second element used in the MA method is smaller than that of the Si aloy powder and is pretentibly at most 10 µm. If it exceeds 10 µm, there is the possibility of the historiess of the layer of the second element within is animed to the surface of the Si aloy provider exceeding 10 µm, and the proportion of the amount of this second element with respect to the amount of the Si layer increases, which is not desirable. There is no particular lower limit on the average particle diameter of the powder of the second element, but ishing into consideration contamination such as oxidation of the powder, the average particle diameter is pretentily at least 1 µm.
The adhering amount of the powder of the second element with respect to the amount of the Si phase powder is prefer

erably on the order of 10:30 persont. [0075] When the adhering layer is formed by the MA method, a small amount (such as 0.1 - 5 wt% and preferably 0.5 - 2 wt% of the powder of the second element) of a ceramic powder may be mixed with the powder of the second element. The carrain cowder used may be formed of one or more allesses such as SiC, SiN₄, TC, TiR, and A₂O₅.

35 The ceramic powder preferably has an average particle diameter smaller than that of the powder of the second element. In this manner, by forming an enveloping material in which a ceramic is finely dispersed, the restraining effect of the enveloping material is strengthened, and the cycle life can be further increased.

[0075] As a method for forming the adhering layer, it is also possible to employ a method in which the powder of the second element is made ocatishe by a brinder, such as an organic binder or the like which can be removed by heat treatown ment in a subsequent step, and is coasted on the Si phase powder, or a method in which a melt of the second element is sprayed on the Si phase powder, or the like.

[0077] After an adhering layer of the second element is formed on the Si phase powder by a suitable method such as those described above, heat treatment is performed. As a result of the diffusion phenomenon which is produced by this heat treatment, Si in the Si phase powder diffuses into the adhering layer and combines with the elements in the adhering layer for forms a solid solution within the adhering layer. As a result, the adhering layer is converted into a layer

amening layer or forms a solid solution warm the amening layer. As a result, the attenting layer is convenient and any of an Si-containing solid solution or intermetable compound, whereby alloy particles according to the present invention in which the surface of the Si phase grains is enveloped in a layer of an Si-containing solid solution or intermetallic compound are obtained.

[0078] For example, in the case where an Ni adhering layer is formed on the surface of Si phase powder by elecsor troless plating and then heat treatment is carried out, Si diffuses into the Ni adhering layer and combines with Ni to form the intermetallic compound NiSi₂. As a result, alloy particles are obtained in which the periphery of Si phase grains is enveloped in an enveloping material of an NiSi₂ phase.

[0079] The temperature of heat treatment for this diffusion should be lower than the solidus temperature of the primary solid solution or intermetalic compound which is formed by this diffusion. From the standpoint of preventing sinset of the product or itself during the heat treatment, a temperature at least 10°C below the solidus temperature is preferable in consideration of notakening the diffusion of elemental Si and the elements in the adhering layer, the lower limit on the heat treatment temperature is preferably at least 500°C. The duration of heat treatment should be sufficient for diffusion. Normally it is at least two hours and noteredably it is at least four hours. The heat treatment atmosphera is

preferably a non-oxidizing atmosphere such as a vacuum or an inert gas atmosphere.

[0080] This heat treatment also serves to remove rapid cooling strains if the Si phase powder is manufactured by the above described rapid solidification and strains generated by the Man embod if this method is used to adhere the adhering layer to the Si alloy phase powder, so additional heat treatment for strain removal is not necessary.

Negative electrode manufacture

[Manufacturing Process A]

[0681] A negative electrode material according to the present invention which is constituted by alloy particles comprising. Sip have gains enviloped in an S-containing solid solution or intermetalic compound can be made into a negative electrode for a non-equipous electrolyte secondary battery using electrode manufacturing processes well known to those skilled in the art.

[0082] For example, a suitable binder can be mixed with a powder of a negative electrode material according to the present invention manufactured in accordance with the above-described first process or second process, and if necessary a suitable electrically conducting powder is mixed therewith to increase conductivity. A solvent which can dissolve the binder is added to the mixture, and it is thoroughly stirred to form a stury, using a homogenizer or glass beads if necessary. The stury can be coased with a doctor blade or the filts on an electrode substrate (serving as a current collector) such as a rolled copper foil or an electrode ladd copper foil. After it is dired, it is compacted by rolling or the like, thereby providing a neasalive electrod for a non-agueous electrolyte secondary battery.

as theretary provising a register electricis or a furniquicionis electrolyse section by a scalar youther [[0083]] Examples of the binder include PVDF (polyvinylidene fluoride), PMMA (polymethyl methacrylate), PTFE (polyterafluoreethylene), water insoluble resins such as styrene-butacliene rubber and the like (which are also insoluble in the solvent used in a non-squous electrylet for a battery), and water soluble resis such as CMC (cathodomethyl-

[0084] The electrically conducting powder may be made of either a carbon material (such as carbon black or graphing) or a metal (such as NI), but a carbon material is preferred. Carbon materials can occlude Li ions between the layers thereod, so in addition to imparting electrical conductivity, they contribute to the capacity of a negative electrode, and they also have oscillent liquid referention. A preferred carbon material is acetylene black.

[0065] When a carbon material is blended in the negative electrode, the carbon material is preferably used in an amount of at least 5 wt% and at most 80 wt% with respect to the negative electrode material of alloy particles according to the present invention. If the amount is less than 5 wt%, a sufficient electrical conductivity is not imparted, and if it exceeds 80 wt%, the capacity of the negative electrode decreases, A more preferred amount is at least 20 wt% and at most 50 wt%.

35 (0066) As a variation on this process, after an adhering layer is formed on Si phase grains according to the above-described Manufacturing Process 2, using powder prior to the performance of heat treatment, a survey can be formed in the manner described above and coated on an electrod substrate. In this case, instead of a drying step, or after final rolling, heat treatment to performed such that Si is diffused in the such dening layer to form an enveloping material of an Si-containing solid solution or intermetallic compound. Namely, the heal treatment step of Manufacturing Process 2 can related to the property of the first process 2 can related to the property of the first process 2 can related to the process 2 can related 3 can relat

[Manufacturing Process B]

[0037] In another manufacturing process for a negative electrode for a non-aqueous electrodyte secondary battery according to the present invention, SI phase powder is subjected to a manufacturing step for an electrode as discarbed above without forming an achiering layer or performing healt reatment, and then formation of an adhering layer of a second element (one or more elements which can form an intermetallic compound or a solid solution with SI) and heat treatment are carried out.

[0088] Namely, in his process, in the same manner as described above, an Siphase powder is mixed with a binder or and if necessary an electrically conducting powder (such as a candom material) to form a slury, which is costad on an electrode substrate, dried, and if necessary compacted by rolling or the like to form a layer of an Siphase powder on the surface of the electrical substrate. Thereafter, a layer of a material containing the second element is adhered to the Siphase powder layer. In this case, since the MA method can not be used to form the adhering layer, a plating method is appropriate. As the plating method, electroless plating can of course be used, but since Siphase powders are already connected to each other to all dive electrical current to pass through all the powders, electricity plating is also suitable. The second element which is plated is present not only on the surface of the Siphase powder layer but enters into the spaces in the Siphase powder layer but enters into the spaces in the Siphase powder.

[0089] Heat treatment is performed after plating, whereby the Si within the Si phase powder diffuses into the adher-

ing layer formed by plating, the adhering layer is converted into a phase of an S-containing solid solution or intermetallic compound, resulting in the formation of a negative electrode made of a negative electrode material according to the present invention of alloy particles comprising is planes or gins at least partially evenloped in a phase of an St-containing solid solution or intermetallic compound. The heat treatment conditions can be the same as the conditions described with respect to Manufacturing Process 2 (the process in which an adhering layer of a second element is formed) for the negative electrode material.

[0090] The thickness of the Si phase powder layer is preferably at most 40 μm. It it exceeds 40 μm. It may be impossible to prevent powderization due to volume changes in the grains at the time of occlusion and release of Lt. The thickness of the adhering layer is preferably at least 100 μm and at most 10 μm. If it is less than 0.1 μm, the restraining effect or on Si phase prains is small, and if it exceeds 10 μm, the amount of the Si phase becomes relatively small, and the capacity for occlusion and release of Lt becomes small. If the thickness of the electrode is to small and the capacity of the regardive electrode is insufficient with a single Si phase powder layer, it is possible to atternatingly coat and plate an Si phase powder layer and an element of an achiering layer, respectively, prior to heat treatment, so as to make a multi-layer structure.

When a negative electrode is manufactured in accordance with Manufacturing Process Bin which a layer of Si phase powder is bromed by ceating on an electrode substate followed by plating to born an adhering layer and heat treatment, only a small amount of elements for the adhering layer are necessary, and it is possible to carry out the formation of the adhering layer in an ordinary electrode manufacturing line, which is advantageous for a decrease in costs, control of investment in equipment, and an increase in productivity.

Non-aqueous electrolyte secondary battery

[0092] Using a negative electrode manufactured in the above-described manner, a non-aquisous electrolyte secordary battery is manufactured. A representative example of a non-aquisous secondary battery is a lithium in secondary battery. A negative electrode material and a negative electrode according to the present invention are suitable for use in a lithium ion secondary battery. However, in theory, they can also be applied to other non-aqueous electrolyte secondary batteries.

10033] As a basic bundur, a non-aqueous electrolyte secondary battery includes a negative electrode, a positive electrode, a separator, and a non-aqueous electrolyte. The negative electrode is one manufactured in accordance with the present invention as described above, and the other elements, the positive electrode, the separator, and the electrolyte may be appropriately selected from those which are well known in the art or which will be developed in the future. 10034] The positive electrode of a tithum in or secondary bar or yis preferably one using an Li-containing transition metal compound as an active material Examples of an Li-containing transition metal compound are compounds expressed by Lift, M,M,Q, or Lift, M,M,M,Q, or Lift, M,M,Q, or Lift, M,M,

[0095] The positive electrode can be manufactured in the same manner as the above-described Manufacturing
Process A for a negative electrode in which a positive electrode material in the form of a powder, a binder, and if necessary a conducting material are formed into a larger, the stury is coated on electrode substrate, and compaction is performed. The average particle diameter of the positive electrode material is preferably in the range of 1 - 30 µm.
PVDF and PTFE are preferred as a binder for the positive electrode, and a carbon material is preferred as an electrically conduction material.

46 [0096] The electrolyste or a lithium ion secondary battery is generally a non-acqueous electrolyst solution of a lithium ion secondary battery is generally a non-acqueous electrolyst solution of a lithium stat as a supporting electrolyst dissolved in an organic solvent Examples of the lithium salt include LOIGH, LIBFA, LIBGFB, LIBGFB,

30 [0037] As the organic solvent, one or more of carbonate seter solvents including cyclic carbonate seters such as ethylene carbonate, procyclere carbonate, and when exhauste and otheir or moroycic carbonate seters such as ethyl methyl carbonate, dimethyl carbonate, and diethyl carbonate, alphalic carbonylate esters such as methyl fromtate, ethyl acetate, and methyl proponeus; - relaciones such as "pubmiscance, chain ethers such as 12-dimethoxychame; cyclic landers such as testralydrofurum, and other various aprotic solvents such as dimethylauthoxide, clooxoranes, amides, attrices, and subranes are pulsed. Perfered solvents are a mixed solvent of carbonate seters, which may be further mixed with an aliphatic carbonylate ester. A mixed solvent of ethylene carbonate and ethyl methyl carbonate is particularly referred.

100981 There is no particular limit on the concentration of the supporting electrolyte in the solvent, but normally it is

in the range of 0.2 - 2 M, and in particular it is preferably in the range of 0.5 - 1.5 M.

[9099] The nonaqueous electrolyte need not be be a liquid (solution) but may be a solid. Solid electrolytes for use in nonaqueous electrolyte secondary batteries are roughly classified into inorganic solid electrolytes and organic solid electrolytes and considerative in longanic solid electrolytes are known to include lithium nitride, halides, and oxo-acid saits. Among others, Lu₃SO₂, Lu₃SO₂-Li-Li-DO₁, Lu₃SO₂-Li-Li-DO₁, Lu₃SO₂-Li-SO₂, brosphouse suifide compounds are effective. As organic solid electrolytes, for example, polyteyine exide, polypropyriere voide, polypriospharea polyazifidine, polyatifylene suifide, polypropylene solid, polypropylene solid electrolytes, or example, polytes of floating the control of the control

[0100] Other compounds can be added to the non-aqueous electrolyte for the purpose of improving charging and oticisharing properties. Some examples of such compounds include intellity phosphits, tipidamolarine, cyclic shers, ethylenediamine, n-glymes, pyridine, hexaphosphortriamide, nitrobenzene derivatives, crown ethers, quaternary ammonium satis, ethylene glovid dislevi derives, and the like.

[0101] The separator serves as an electrically insulating membrane for electrically insulating the positive electrods and the negative electrods, and it also contributes to retention of the non-equeous electrolys. An electrically insulating microporous membrane having a high ion permeability and a suitable mechanical strength is used as the separator. In order to increase the safety of the battery, one having pores which close up when a fixed temperature is reached to increase the resistance is orgenered.

[01022] Taking into consideration resistance to organic solvents and hydrophobiotix, a microporous sheet, a nonwoven fabric, a woven fabric, or the like made from a polyotelin polymer or glass fibers is often used as a separator. The zopic size of the separator is preferably on the order of 0.01 - 1 µm so that materials which are detached from the electrode can not pass through the separator. The thickness of the separator is generally on the order of 10 - 300 µm. In central, it is rederred that the corosity of the separator be in the rance of 30 - 80 %.

[0103] As one type of lithium secondary battery, there is a battery having a structure in which a positive electrode and a negative electrode include a polymer which absorbs and retains a non-aqueous electrolyte solution, and the same non-aqueous electrolyte solution is absorbed and retained in a polymer of a separator. In this case, a copolymer of vinylideneflucride and hexafluoropropylene is particularly preferred as a polymer material for absorbing and retaining an organic electrolyte solution.

[0104] There is no particular restriction on the shape of the non-equeues electrolyte secondary battery. It can be optimidical, rectangular, coin shaped, button shaped, sheet shaped, laminar, flat, or a large shape for an electric automobile. A non-equeues electrolyte secondary battery according to this invention, although not limited thereto, can be used in a portable information terminal, a portable electronic device, a small electric power storage device for household use, a motorcycle, an electric automobile, and the file.

Industrial Applicability

[0105] A negative electrode material according to the present invention or a negative electrode material according to the present invention or an engative electrode material manufactured according to the process of the present invention or a non-squous electrybe secondary battery using the negative electrode uses an Si phase, which has a high theoretical capacity, as an active material (an Li occluding substance) for a negative electrode, so it has a high quespicty, in addition, due to the perhipport OS [bhases grains being eventoped in a phase of a Si-containing solid solution or intermetallic compound and volume changes of the fine of charging and discharging in the asso of an Si phase being used as a negative electrode active material are effectively prevented, so it is difficult for a decrease in cycle life due to powderization to take loace, and the vical life is excelled.

[0166] The present invention can provide a negative electrode material for a non-sequeous electrolyte secondary battery and a negative electrode, the material having an extremely high discharge capacity compared to a negative electrode material made from a conventional carbon material and a good cycle life of at least 80%, and being able to contribute to increases in performance of lithium ion secondary batteries and other non-acqueous electrolyte secondary batteries.

50 Examples

[0107] A negative electrode test used to evaluate negative electrode materials and negative electrodes for nonaqueous electrolyte secondary batteries will be described.

55 (Negative Electrode Test)

[0108] A powdery negative electrode material to be tested was classified to obtain a powder with an average particle diameter of 30 µm. To the powder, poly(viry)tidene fluoride) was added as a binder in the proportion of 10 wt% based

on the weight of the powder and then N-methylpyrotichore was added as a solvent also in the proportion of 10 wth to the dissolver her polyrivityficane function) brinder. To this wature, a powder of a carbon material (acetylene black) was added as an electrically conducting powder in the proportion of 10 wth, based on the weight of the mixture and thoroughly mixed to obtain a uniform survey.

- 5 [0109] The sturry was applied to an electroplated copper foil having a thickness of 30 µm, dried, and compacted by rolling, after which it was purphed using a punch having a diameter of 13 mm. The resulting disk members were used as negative electrodes for nonaqueous electrolyte secondary batteries. The thickness of a layer of the negative electrode meterial formed on the coper foil was about 100 µm.
- [0110] The properties of the negative electrodes as single electrodes were evaluated with a so-called three-electrode and reference electrode the made of tithism metal. As an electrofyte solution, a 1M solution of LIPF₆ as a supporting electrofyte dissolved in a mixed solvent of ethylene catcomate and dimethoxyetheriane at a ratio of 11 viasu used. Measurements were made at 25°C in a microsphere having a dew point of around -70°C while the cell was placed in a device such as a glove box capable of maintaining an inert atmosphere. [0111]
- (9 11) Charging was meanly period at a 1/10 charge not ready. I.e., which a current require to reach a full charge by charging for 10 hours, until the negative electrode had a potential of 0 V with respect to the reference electrode. Then, discharging was carried out with the same current until the reference electrode had a potential of 2 V with respect to the negative electrode. The discharge capacity in this first cycle at this time was used as the discharge capacity of the negative electrode former from the negative electrode material. The charging and discharging cycle was repeated, the clascharge capacity was measured at the 300th cycle, and the cycle life was measured by the following equation in serms of % capacity retention after 300 cycles. A cycle life of at least 90% was considered acceptable.

Cycle life (%) = (discharge capacity in 300th cycle/discharge capacity in 1st cycle) × 100

- [0112] The discharge capacity in the 1st cycle is the capacity during the discharging following the first charging, and the discharge capacity in the 300th cycle is the capacity during the discharging following the 300th charging.
 - [0113] Negative electrodes prepared by the above-described Manufacturing Process B were evaluated in the same manner as above using the above-described three-electrode cell.
- [0114] In all the examples, the discharge capacity is expressed in the units mANoc (in which co is the volume of the negative electors plate calculated from the area of the negative electors plate and the thickness of the negative electors material).

Example 1

[0115] This example illustrates the case in which a negative electrode material according to the present invention is manufactured in accordance with the above-described Manufacturing Process 1 (rapid solidification method). The gas atomization, the single-rollier quenching, and the plasma relating electrode method were used as cooling methods. [0116] First, the solidification speed or the cooling rate at the time of solidification of each method was measured using an AI-4 wWS Cu allow.

40 [Measurement of cooling rate]

(Single-roller quenching)

[9117] A single roll comprising a core made of carbon selet with a diameter of 20 mm and an outer peripheral portion made of Cu with a thickness of 10 mm was rotated at a rotational speed of 2,000 gmm. A mothern are material of an Al-4 wrifs Cu alloy was dropped on the circumferential surface of the roll and solidified. The solidified material was observed with an optical microscope to measure the distance between secondary arms of dendrite, and the cooling rate was determined based on the distance.

50 (Gas atomization)

[0118] An Ar (argon) gas was blown at a pressure of 40 kg/cm² through a discharge nozzle, and a molten raw material or an N-14-w% Cu alloy was dropped into the blown gas at a rate of 150 g/minute and soldified. Using a microscope to observe the solidified particles which were formed, the cooling rate was determined in the same manner as for the single-roller quenching.

(Rotating electrode method)

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[0119] A molten raw material comprising an Al-4 wris Cu alloy was cast to produce an electrode with a diameter of 20 mm. This was mounted on the anole side in an apparatus for the rotating electrode method and rotated at a rotational speed of 500 mm, and solidified particles were obtained. The cooling rate was determined by the same method as described shows.

[0120] For comparison, the cooling rate was determined by the same method as described above for a specimen which was solidified by casting into an inqut using the same molten raw material as above.

[0121] The results are shown in Table 1.

TABLE 1

Cooling Method	Cooling Rate (°C/sec)
Single roller quenching	10 ³ - 10 ⁵
Gas atomization	10 ³ - 10 ⁵
Rotating electrode	10 ²
Ingot casting	30

[0122] As can be seen from Table 1, each of single-roller quenching, gas atomization, and rotating electrode methnods had a cooling rate of all east 100°C per second and performed rapid solidification. Among these, single-roller quenching and gas atomization had a high cooling rate of at least 100°C per second. On the other hand, the cooling are tab for ingol casting was 50°C per second and wes smaller than 100°C per second.

[Manufacture of a negative electrode material]

[0123] Using an N-S2 wf%. Si alloy, the effect of the cooling rate (cooling method) on the charging and discharging properties with L is a negative electrode material for a nonaqueous electrody's executory battery was investigated. [0124] A single element and a mother alloy were suitably blended so as to obtain a composition of 48 wf%. Ni and S2 wf%. SI, and they were method in a high frequency induction mething furnace to make a unition meth, which was used as a test material for each cooling method. In the rotting electrode method, an electrode which was obtained by cast-ing the alloy meth into the form of a round rod having a diameter of 20 mm was used as a test material. For each cooling method, the rounds are cooling attractive was an around strongshere.

[0125] A portion of the solidfied material obtained by each cooling method was subjected to heat reatment in an argon atmosphere at 500° C for four hours. The primary Ni-Si intermetallic compound which precipitates during the solidification of an Ni-Se Wris Si alloy and which has the possibility being used as an enveloping material is NiSig. The solidification of this NiSig. Se 930° C. After heat treatment the solidified materials obtained by the single-roller quenching material and their look of the provided to continue.

(D125) Using test materials obtained by heat treatment of alloy particles obtained by each method (heat-treated materials) and test materials which were not heat-treated (as-solidifed materials), the above-described negative electrode test was carried out and the discharge capacity and the cycle life were evaluated. In addition, the cross section of the solidified material before grinding in the cases in which grinding was performed obtained by each cooling method was investigated by SEM. In each case, as shown in Figure 4, the structure was one in which the matrix was an WSig-phase and Si phase grains were present therein, either enveloped or not enveloped by an NSI phase. The avverage diameter and the overall weight proportion (wRS) of the core of Si phase grains was investigated by SEM in photograin (the avverage diameter was the avverage value of 100 randomly selected particles). The results are shown together with the results of the negative electrode test in Table 2.

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TARIE 2

	IABLE 2										
ſ	Cooling Method	Н	eat treatment	(900°C × 4h	r)	As-solidified(no heat treatment)					
Ī		Discharge capacity(1)	Cycle life (%)	Ci		Discharge capacity(1)	Cycle life (%)	Si phase	(2) grains		
Г				μm	wt%			μm	wt%		
n	Single- oller Juenching	750	90	7	6	950	88	1	10		
	Gas atomi- ation	750	90	12	6	950	89	1	10		
e	Rotating electrode nethod	760	80	22	6	950	81	2	10		
	ngot nethod	740	68	52	6	950	48	51	10		

¹Units of discharge capacity are mAh/cc

- 5 [0123] Looking at the results of the negative electrode tests, the value for the discharge capacity of a negative electrode made by the comparative ingot method was not so inferior to that for the present invention. However, it is important to note the cycle file. For the process of the present invention in which the average diameter of Si phase grains was smaller than 40 µm, the cycle file in each case was a high value of at least 50%. In contrast, for the comparative process, at was an unacceptable value of 40% or 65%. Among the examples of the present invention, the notified quenching
- 40 and atomization methods produced Si phase grains having a small average diameter and giving a high cycle life of 89%. [0129] Comparing heat restand materiels and as soldified materials, heat treatment caused the average diameter of an Si phase to increase and the weight ratio of Si phase grains to decrease. The as-solidified material for which the Si phase had a maller average diameter and a higher weight ratio had a relatively high discharge capacity. The cycle life of the as-solidified material was either the same or only slightly inferior to that of the heat treated material due to the effect of line discorption of the Si phase prains.

Example 2

[0130] Using an Ni-S2 w75 Si alloy, a negative electrode meterial was manufactured by gas abmitzation in the same or manner as described in Example 1 except that the heal treatment temperature was changed. The average diameter of the Si phase grains of the resulting negative electrode material and the negative electrode test results are shown in Table 3 together with the heat treatment temperature.

²For Si phase particles, μm indicates average particle diameter, wt % is weight % in material

Table 3

Heat treatment tempera- ture(°C)	Discharge capac- ity(mAh/cc)	Cycle life (%)	Average diameter of Si phase grains (µm)
· 900	750	90	12
800	745	90	8
700	745	90	3
600	740	92	2
No heat treatment	950	89	1
985	750	69	53

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As shown in Table 3, in the inventive process in which the heat treatment temperature was at least 10°C below the solidus temperature of 993°C of NiSio, which is the primary intermetallic compound formed during solidification of an Ni-52 wt% Si alloy, the average diameter of Si phase grains was no more than 40 µm, and the cycle life in 20 each case was at least 90%. In contrast in the comparative method in which heat treatment was performed at a temperature 8°C below the solidus temperature, the average diameter of Si phase grains exceeded 40µm due to the growth of the Si phase grains as a result of heat treatment, so restraint of the Si phase grains by the enveloping layer to prevent changes in volume of the grains could not work effectively, and the cycle life did not reach 80%.

25 Example 3

[0132] A negative electrode material was manufactured by gas atomization in the same manner as described in Example 1 except that the composition of the Ni-Si alloy raw material (expressed as wt% of Si) was changed (with heat treatment at 900°C for 4 hours, or without heat treatment). The average diameter of the Si phase grains of the negative 30 electrode material which was obtained and the results of the negative electrode tests are shown in Table 4.

Toblo 4

			180X9 4			
Wt% Si	Heat treatment	Wt% Si phase grains	Discharge capacity (mAh/cc)	Cycle life (%)	Average diame- ter of Si phase grains (µm)	Comments
52	Yes	6	750	90	12	this invention
	No	10	950	87	1.0	i
54	Yes	10	820	88	13	this invention
	No	17	1035	84	1.5	1
56	Yes	14	950	83	12	this invention
	No	18.2	1200	80	2.0	1
58	Yes	18	1180	81	12	this invention
	No	22	1495	80	2.3	
	Carbon electr	ode	450	80	-	Comparative electrode

As shown in Table 4, regardless of whether heat treatment was carried out or not, as the weight ratio represented by Si phase grains increased, the discharge capacity increased but the proportion represented by the envelop-55 ing material which restrains volume changes decreased, so the cycle life had a tendency to gradually decrease. Furthermore, for the same amount of Si, the material which had been heat treated had a lower discharge capacity, but it had a somewhat higher cycle life. However, compared to a presently used carbon electrode, the discharge capacity and the cycle life were comparable or mostly much higher.

Example 4

[0134] Using gas atomization in the same manner as described in Example 1, a substitution solid solution alloy was manufactured by substituting a portion of the N in an N in 52 w/K Si alloy with other elements. A portion of the resulting alloy was heat treated in argon atmosphere at 850°C for 8 hours. A negative electrode test was carried out using an assolidified alloy and a heat-freated alloy. The alloy composition and the results of the negative electric tests are shown in

TABLE

10		ABLE 5										
	Alloy Com- position	Heat treatm	ent (800°C ×8	hr)		As-solidified(no heat treatment)						
15		Discharge capacity(1)	Cycle life (%)	Si phase ₍₂₎ grains		Discharge capacity ₍₁₎	Cycle life (%)	Si phase	₂₎ grains			
				μm	wt%			μm	wt%			
	Ni-52Si	750	90	12	6	950	89	1	10			
20	Ni-5Fe- 52Si	755	92	12	6	955	90	2	10			
	Ni-5Co- 52Si	750	94	12	6	950	93	3	10			
25	Ni-5Mn- 52Si	740	91	10	6	940	91	2	10			
	Ni-5Cr- 52Si	740	93	11	6	940	90	1	10			
30	Ni-5Cu- 52Si	750	92	12	6	950	94	1	10			

Units of discharge capacity are mAh/cc

- 35 [0135] In Table 5, Ni-SFe-52Si, for example, represents a 43 w/% Ni-5 w/% Fe 52 w/% Si alloy. The intermetallic compound NiS₂ and a portion of the Ni in NiSi is substituted by Fe in solid solution. The same as for Fe applies for Co, Mn. Cr. and Cu.
- [0136] As shown in Table 5, even when the enveloping material is a solid solution, a discharge capacity appropriate for the weight percent of the Si phase is obtained, and the cycle life is also satisfactory. Furthermore, as in Example 1,
- 40 the Si phase is minute, and the as-solidified material having a high proportion thereof had a higher discharge capacity than the heat-treated material. The cycle life was good in either case.

Example 5

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- 46 [0137] Using gas atomization in the same manner described with respect to Example 1, a negative electrode material and a text heater attent was manufactured white varying the type and the amount of the second element which forms an alloy with 5 and the heat treatment temperature. The composition of the alloying raw materials used, the solidus temperature of the principle intermetallic compound predictated during the solidification of this bitary galox, and the heat treatment temperature emboyed are shown in Table 6 loopther with the average diameter.
- so eter of the Si phase grains of the resulting negative electrode material and the negative electrode test results.

 $^{^2\}mbox{For Si phase particles,}~\mu\mbox{m}$ indicates average particle diameter, wt % is weight % in material

TABLE 6

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TABLE

As-solidified (no heat treatment)	Discharge Cycle Average diameter Discharge Cycle capacity life of Si phase capacity life (addycc) (90 grains (um) (addycc) (90	577 94 3 630 89	898 94 2 1070 90	750 90 1 960 89	692 89 2 850 88	654 86 3 990 92	620 87 3 820 91	713 86 3 960 88	587 85 2 750 85	585 86 2 750 86	578 87 3 840 86	494 84 3 670 87		865 84 2 1050 88
Heat treated	Average diameter of Si phase grains (\mu n)	12	11	12	11	18	91	15	13	=======================================	11	9	12	-
	Heat treatment temperature (C)	906	990	906	006	1200	0011	1280	1100	1100	1100	009	1200	
Comocition	at solidus temperature	MeSit	CaSi	NiSi	FeSiz	CoSir	Marsin	TiSiz	PrSi.	KdSi	CeSit	CuSir	CrSi ₂	
Sign	Tempera- ture (C)	946	1030	868	937	1259	1150	1330	1212	1197	1200	802	1305	
Composition of	rar materials	Mg41Si	Ca62Si	Ni52Si	Fe63Si	Co65Si	Mn55Si	Ti77Si	Pr52Si	Nd52Si	Ce60Si	Cu20Si	Cr74Si	

" The number before Si indicates the wt % of Si (for example, Mg41Si indicates a composition of 59 wt% Mg and 41 wt % Si).

[0138] As shown in Table 6, as a negative electrode material was manufactured with varying the element forming an intermetallic compound or solid solution with Si, the discharge capacity varied, but the cycle life was good in each case. The discharge capacity for the as-solidified material was higher.

Example 6

[0139] This example illustrates the case in which a negative electrode material according to this invention is formed in accordance with the above-described Manufacturing Process 2 (adhering layer-forming method). As described below. Samples 1-7 of allow particles were prepared.

- (1) A spherical-shaped SI powder obtained by argon gas atomization and having an average particle diameter of approximately 3 up in were plated with nided to a thickness of approximately 1 up in using a commercially available alkaline electroless nickel plating solution. The resulting Ni-plated SI powder was then heat treated in an argon gas atmosphere at 700°C for 4 hours to obtain alloy particles with an average particle diameter of 32 µm. The coss section of the powder after heat treatment was observed with an optical microscope, and fives seen that SI powder was enveloped in an NiSig layer (the composition of which was determined by EPMA) with a thickness of approximately 1 µm. This regards electrode material was made Sample 1. The solduct sempeature of the NiSig enveloper material was 983°C, as shown in Example 1 and Table 5. The heat treatment impretative was at least 10°C.
- lower than this solicius temperature.

 (2) A spherical Si powder which had been prepared by gas atomization in the same manner as in Sample 1 was subjected to the MA method along with an Ni powder having an average particle diameter of 1 µm for 1 en hours in a planetary ball mill (Pristen Model P-5) to form an achering layer of the Ni powder on the surface of the Si powder. Healt treatment was then performed in the same manner as for Sample 1 to obtain alloy practices with an average particle diameter of 32 µm. A layer of MSB, with a thickness of approximately 1 µm which enveloped the surface of the Si powder was formed. This enables electrode material was made Sample 2.
- (3) An N-Si alloy powder having a chemical composition with a weight ratio of N in Si of 20.80 and an average particle diameter of 30 µm was prepared by gas atomization in the same manner as for Sample 1. The alloy powder was subjected to electroless N jalating to form an N layer with a thickness of approximately 1 µm on the surface of the powder and subsequent heat treatment both in the same manner as for Sample 1. The heaty-related powder which had an everage diameter of 32 µm included a core of Si phase grains of a structure in which an NiSty phase was precipitated in an Si phase matrix and the core was enveloped by an NiSty layer having a thickness of approximately 1 µm. This negative electricion material was made Sample 3.
- (4) An Si powder prepared by gas atomization in the same manner as for Sample 1 and having an average particle claimates of approximately 30 jum was subjected for 10 hours to the AlM ametoin an japanetary ball mill (Fritch Model P-5) with a powder mixture of Ni powder having an average particle dismeter of 1 jum and 14% of TIC powder manufactured by Waleo Juryskut having an average particle dismeter of 0 gain to adhere the mixed powder to the surface of the Si powder. Thereafter, heat treatment was performed in an Ar gas atmosphere at 700°C for 4 hours to obtain alloy particles. This negative electrode material was made of sample 4.

When the cross section of the powder of Sample 4 after heat treatment was observed on an optical microscope, it was found that an enveloping layer made form an NSig-phase with a thickness of approximately 1 mm was formed on the surface of the SI powder. Fina TiO precipitates with a size of 0.1 µm or less could be observed within he NSig-phase. (The NSig-phase was determined by the weight ratio Of N and Siby EMPA analysis. The fine pre-cipitate had a size smaller than the beam diameter used in the EMPA analysis, but Ti and C could always be detected, so the so resume to be TiO.

The precipitated particle size of the TTC phase was smaller than the particle size of the TTC powder which was used. This was thought to be because the 1TC powder used (in which primary particles cohered to become 0.6 µm powder) are distribugated into primary particles (at most 0.1 µm) by the machanical energy of the MA method. (5) in the same manner as for Sample 4, in place of TTC, an SIC powder manufactured by Walso Junyaku with an average particle diamster of 0.2 Pm was mixed with the Nipowder at weight ratio of 1% and subjected to the MA processing, and heat treatment was performed under the same conditions to obtain a negative electrode material, which was made Sample 5.

- (6) For comparison, an Ni-80 weight's, Si alloy was manufactured by the inpot method and was subjected to heat treatment in an Ar gas atmosphere at 10°0°C to right hours. The resulting alloy had a structure in which an NiSi₂ phase was precipitated in an Si phase matrix, but the NiSi₂ phase was coarse. The ingot was subjected to grinding in an inert atmosphere and was classified to obtain a powder with an average particle diameter of approximately 32 µm. Because the NiSi phase was coarse, the resulting powder had various structures including that with just an Si phase, that with both an Si phase and an NiSi₂ phase, and that with just an NiSi₂ phase. This Ni-Si altoy powder was made Samule 6.
- 55 (7) An ingot powder of an N-80 wtfs. Si alloy having an average particle diameter of 30 µm which was prepared in the same method as to Sample 6 was subjected to Ni plating to electrodes plating and followed by hate treatment in the same manner as for Sample 1 to produce alloy particles. The core structure of this powder was the same as for Sample 6. An envision; martisel doubtlining an Nisio is not Sich phase was formed on the surface of the powder.

The NiSi₂ phase present in the core of Si phase grains was coarse, as for Sample 6. A powder (average particle diameter of 32 µm) of these allow particles was made Sample 7.

[0140] The alloy particles of each of Sample 1 through Sample 7 had an average particle diameter of approximately 22 µm. It was confirmed that the chemical composition for Samples 1, 2 and 4-49 was NisiS = 20.93, and for Samples 3 and 7 was NisiS = 36:64. The results of negative electrode tests using these samples of negative electrode materials are shown in Table 7.

Sample No.	Discharge capacity (mAh/cc)	Cycle life (%)	Comments	
1	1950	90	this invention	
2	1950	83	this invention	
3	1350	90	this invention	
4	1930	92	this invention	
5	1920	92	this invention	
6	1940	25	Comparative	
7	1340	85	this invention	

28 [0141] As shown in Table 7, the magnitude of the discharge capacity principally depends on the weight persont of SI. The discharge capacity was high for Samples 1,2, and 46 having a high Si content. However, Sample 6, which was a comparative example without an enveloping material, had an extremely short cycle life and was not acceptable. On the other hand, in the case in which an enveloping material was formed around an SI phase grain and the property of the present invention, the cycle life had a good value of at least 80%. In particular, Samples 4 and 5 which had finely dispersed TIC or SIG in an enveloping material had the best cycle life.

Example 7

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[0142] In the same manner as for Sample 1 of Example 6, an Si powder was subjected to electroless nickel plating, after which het treatment was carried out to mantadruse a negative electrod ensteried made from alloy particles in which SI phase grains are enveloped in an NISig phase. However, the concentration of the electroless nickel plating solution was varied to give a different plating histoness. The results of negative electrode tests performed on this negative electrode naterial are shown in Table 8 together with the results of the veight ratio of the SI phase grains. The weight ratio of \$1 \text{ghase} are shown in Table 8 together with the results of the veight ratio of the SI phase grains. The weight ratio of \$1 \text{ghase} are shown in Table 8 together with the results of the veight ratio of the SI phase grains of \$1 \text{ghase} are shown in Table 8 together with the results of the veight ratio of the SI phase grains are similar to the state of the shown in table \$1 \text{ghase} are shown in Table 8 together with the results of the veight ratio of the SI phase grains are shown in Table 8 together with the results of the veight ratio of the SI phase grains are shown in Table 8 together with the results of the veight ratio of the SI phase grains are shown in Table 8 together with the results of the veight ratio of the state of the shown in Table 8 together with the results of the veight ratio of the state of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the results of the shown in Table 8 together with the shown in Table

TABLE 8

Plating thickness (µm)	Weight percent Si phase grains	Discharge capacity (mAh/cc)	Cycle life (%)
0.1	98	2800	80
0.15	94	2600	80
0.8	72	2200	80
1.5	50	1700	85
3.5	45	1600	85

[0143] As shown in Table 8, when Manufacturing Process 2 is employed, the weight ratio of Si phase grains can be as high as 99 wt% and a good cycle life is obtained in such a case. The higher is the proportion of Si phase grains, the higher is the discharge capacity, so with Manufacturing Process 2, an extremely high discharge capacity exceeding

2000 mAh/cc can be realized.

[0144] Accordingly, taking into consideration manufacturing equipment and manufacturing costs, by suitably using Manufacturing Process 1 or 2, a negative electrode material for which the weight ratio of Si phase grains is at least 5 with and us to 99 w/% can be manufactured.

Example 8

[0145] Except for varying the heat treatment temperature, a negative electrode material made of alloy particles in which Si phase grains are enveloped in NSig phase was manufactured in the same manner as for Sample 1 of Example 10. The results of negative electrode tests are shown in Table 9 together with the heat treatment temperature and the average diameter of Si phase grains. The weight rallo of Si phase grains in this case was approximately 50 wt% for each material.

TARIE O

15	IABLE 9								
	Heat treatment tempera- ture (°C)	Average diameter of Si phase grains (µm)	Discharge capacity (mAh/cc)	Cylcle life (%)					
20	985	Sintered during heat treatment so could not be tested	•						
	830	27	1950	92					
	700	26	1950	90					
	600	20	1940	90					
25	500	15	1940	88					
	Note: The solidus tempera	ature of NiSi ₂ was 993°C.							

30 [0146] When the heat treatment temperature was 985°C, which was only 8°C lower than the solidus temperature of 993°C, the powder was sintered and could not be used as a test material. Material which was treated in accordance with the present invention had a high discharge capacity and its ordel life was also could.

Example 9

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[0147] In the same manner as in Example 7, Si powder which was prepared by gas atomization and had an average particle diameter of 30 µm was subjected to electroless plating with various metals, after which heat treatment was carried out at the temperatures shown in Table 10 (for four hours in each case), and a negative electrode material made from alloy particles in which SI phase grains were enveloped in the indicated intermetalic compound or solid solution

40 was manufactured. The plating thickness of each element was adjusted depending on its specific gravity so that the weight ratio of St phase would be 50 wt% in each case. The results of negative electrode tests on this negative electrode material are also shown in Table 10.

[0148] For comparison, the results of a negative electrode tests performed on a carbon material as a typical presently used negative electrode material are also shown.

TABLE 10

	Plating element	Solidus tempera- ture (°C)	Heat treatment temperature (°C)	Composition at solidus tempera- ture	Discharge capac- ity (mAh/cc)	Cycle life (%)
	Mg	946	700	MgSi ₂	1700	90
	Ca	1030	800	CaSi ₂	1700	90
	Fe	937	700	FeSi ₂	1680	85
	Co	1259	950	CoSi ₂	1690	85
	Ni	993	700	NiSi ₂	1700	90
	Mn	1150	900	Mn ₄ Si ₇	1690	87
	Ti 1330		950	TiSi ₂	1700	84
	Pr	1212	950	PrSi ₂	1680	85
	Nd	1197	950	NdSi ₂	1700	83
•	Ce	1200	950	CeSi ₂	1700	84
	Cu	802	600	CuSi ₂	1700	84
	Cr	1305	950	CrSi ₂	1700	80
	W	1390	1000	WSi ₂	1700	80
	*AI	577	500	Al	1850	80
	*Pb	328	300	Pb	1840	80
	Carbon material	-		-	450	80

[&]quot;The coating layer was an Al-Si or Pb-Si solid solution.

[0149] As shown in Table 10, even if the elements of the adhering layer formed by plating are varied, a negative electrode material having a higher discharge capacity compared to carbon can be obtained. In addition, in each case st the cycle life was a good value of at least 80%. For those cases in which the enveloping material is a solid solution of All or Pb which itself can occlude and release it, the discharge capacity was comparatively large.

Example 10

- 40 [0150] This example illustrates an example of manufacturing a negative electrode by Manufacturing Process B. [0151] St powder having a particle diameter of at most 25 µm and an everage particle diameter of 15 µm was prepared by argnon gas attraitation, and in the same manner as described with respect to the negative electrode tests, a surry was prepared from the Si powder having no adhering layer. This slurry was coated to a thickness of approximately 25 µm on an electroplated cooper foll and rided to form an Si powder layer on the copper fol.
- 45 [0152] The Si powder layer was subjected to electroless or electrolytic plating with the elements shown in Table 11 to form an adhering layer on the surface of the Si powder layer. Thereafter, heat treatment was carried out in an argon atmosphere at the temperatures shown in Table 11 (with duration of four hours) to produce a negative electrode for a nonaqueous electrolyte secondary battery. The thickness of each plated adhering layer was 3 µm. The weight ratio of Si phase grains varied somewhat depending upon the specific gravity of the enveloping material formed by plating and set treatment, but in each tesse it was around 50 w/%.
 - [0153] The properties of the negative electrode manufactured in this manner were measured in a tree-electrode cell in the same manner as described above with respect to the negative electrode test. The results of measurement are also shown in Table 11.

TABLE 11

	(ADLE 11									
5	Adhered element	Plating method	Solidus tempera- ture (°C)	Heat treatment temperature (°C)	Discharge capac- ity (mAh/cc)	Cycle life (%)				
	Ni	Electroless	993	700	1700	85				
	Fe	Electrolytic	937	700	1680	80				
	Co	Electroless	1259	950	1700	85				
10	Mn	Electrolytic	1150	900	1690	82				
	Ti	Electrolytic	1330	950	1700	80				
	Pr	Electrolytic	1212	950	1690	80				
15	Nd	Electrolytic	1197	950	1710	80				
	Ce	Electrolytic	1200	950	1700	80				
	Cu	Electroless	802	600	1680	80				
20	Cr	Electrolytic	1305	950	1690	80				
		Carbon	450	80						

[0154] As shown in Table 11, also in accordance with Manufacturing Process B in which an Si powder layer was select formed and then subjected to planting to form an adhering layer of a second element followed by heat treatment to form an enveloping material, a negative electrode having a good discharge capacity and cycle life could be manufactured.

Example 11

[0155] In the same manner as in Example 9, an adhering layer of Ni, Mg, Ca, Co, Fe, or W was formed on the surface of Si powder by electroless plating, and heat treatment was performed to obtain a negative electrode material made form alloy particles. Using this material, a lithium ion secondary battery was assembled, and a battery test was carried out as described below. For comparison, a battery using a presently used carbon material as a negative elec-

35 trode was manufactured in the same manner, and similar tests were carried out. The results are shown in Table 12. [0156] Figure 2 schematically shows a vartical cross section of a cylindical nonaqueue electrivity escondary battery used in this example. In Figure 2, 1 is a battery case made by forming of a stainless steel plate having resistance to an organic electrivity is solution, 2 is a sealing plate equipped with a safety valve, and 3 is an electrically insulating packing, 4 is a group of electrived plates. A positive electrod plate 5 with a separator

40 7 therebetween are wapped a plurality of turns into a spiral shape and are housed within the case. An aluminum lead Sa for positive electrode extends from the positive electrode pitate 5 and is connected to the sealing opening pitate 2, and a nickel lead 6s for negative electrode extends from the negative electrode pitate 6 and is connected to the bottom of the battery case 1.8 is an electrically insutating ring provided on the top and bottom, respectively, of the electrode pitate or our better pitate for our better pitate pitate

45 [0157] The positive electrode plate 5 was manufactured in the following manner.

[0183] First lithium carbonate and cobatt carbonate were mixed in prescribed proportions, and then this mixture was sintered in air at 900°C for a sufficient length of time to give LiCoO₂ serving as an active material for positive electrode. To 100 parts by weight of powder of LiCoO₂, three parts by weight of acetylene black as an electrically confucting assistant and five parts by weight of a fluoroesin binder were mixed, and the mixture was dispersed in N-methylpyrroso idione to form a pasts. The psach was coasted on bind surfaces of alminimum file having a trickness of 0.02 mm and

leading to torm a passe. The passe was coaled an our suitaves or automatin on harmy a shortess of vices in and dried to produce a positive electrode plate with a thickness of 0.130 mm, a width of 35 mm, and a length of 270 mm. An aluminum piece was attached as a positive electrode lead.

0159] The manufacturing process for a negative electrode plate 6 was as follows.

[0169] 100 parts by weight of a negative electrode material made from alloy particles prepared in accordance with se Example 9 were mixed with 10 parts by weight of a styrene-butadiene rubber binder and three parts by weight of acetylene black as an electrically conducting additive, and the mixture was dispersed in an aqueous solution of carboxymethylcellulose to form a paste. The paste was coated on both surfaces of a copper foil having a thickness of 0.015 mm and dried to produce a negative electrode place with at historiess of 0.2 mm, a width of 37 mm, and a length of 300 mm.

[0161] The positive electrode plate and a negative electrode plate manufactured in the above-described manner were wrapped into the shape of a spiral with a separator disposed therebetween and then housed in a battery case with a diameter of 13.8 mm and a height of 50 mm. A solution of LIPF₆, dissolved with 11M concentration in an equal volume of mixed solvent of eithylene carbonate and elethyl methyl carbonate was used as an electrody a solution. This solution was poured into an electrode plate group 4, and then the opening of the battery was sealed with a lid to manufacture test batteries A-F. (the elements used for plating were respectively Ni, Mg, Ca, Fe, Co, and W). A test battery G in which the negative electrode material was a carbon material was manufacture in the same manufacture in the same manufacture.

[0162] These batteries were subjected to a charging and discharging cycle test with a charge and discharge current or 100 mA and with a charge cut-off voltage of 4.2 volts and a discharge cut-off voltage of 25 volts. The charge and discharge capacity was measured on the first cycle, the discharge capacity was measured after the 500th cycle, and the proportion (%) of the discharge capacity on the 500th cycle with respect to the discharge capacity on the first cycle was determined as the cycle life.

[0163] The charge and discharge capacity on the first cycle, the discharge capacity after the 500th cycle, and the cycle life of these batteries are shown in Table 12.

Table 1

ſ	Battery Symbol					
20		Plating element	Charging capacity 1st cycle	Discharge capacity 1st cycle	Discharge capacity 500th cycle	Cycle life
- 1	А	Ni	945	900	834	93
- 1	В	Mg	923	879	791	90
25	С	Ca	935	890	810	91
~	D	Fe	820	780	679	87
- 1	E	Co	840	800	704	88
	F	W	800	760	654	86
30	G.		530	500	400	80

Carbon material negative electrode

56 [0164] For each of the elements adhered to the Si powder, the nonaqueous electrolyte secondary batteries according to the present invention had a much higher capacity than the comparative battery using a carbon material as a negative electrode material, and they also had a high cycle life, so the results thereof were good.

Claims

- 1. A negative electrode material for a non-aqueous electrolyte secondary battery, which is made from alloy particles of a structure comprising one or more Si phase grains and a phase of an Si-containing solid solution or intermetallic compound which at least partially envelops the Si phase grains, wherein the average particle diameter of the alloy particles is at least 0.1 µm and at most 50 µm, and the Si phase grains constitutes at least 5 wt% and at most 59 wt% of the negative electrode material.
- 2. A negative electrode material for a nonaqueous electrolyte secondary battery as claimed in Claim 1, wherein the Si-containing solid solution or intermetalitic compound is made from 5 and at least one element selected from the group consisting of Group 2A elements, transition elements, Group 3B elements, and Group 4B elements excluding Si from the fores from periodic table.
- 3. A process for manufacturing a negative electrode material for a nonsqueuse electrolyte secondary battery, which is made from alloy particles of a structure comprising one or more Sphase grains and a phase of an Si-containing solid solution or intermetallic compound at least partially enveloping the Si phase grains, characterized by comprising a step of solidifying an ellor for an waterials for the alloy particles by coolings as as to obtain a cooling rate of at least 100°C per second and forming an alloy including Si phase grains and a phase of an Si-containing solid solution or intermetallic compound which at least anneality envelous the Si phase sorgina.

- 4. A process of manufacturing a negative electrode material for a nonaqueous electrolyte secondary battery as claimed in Glaim 3, wherein the coding at a risk of at least 100°C per second is carried out by a method selected from the group consisting of the atomization method, the roller quenching method, and the rotating electrode method.
- 5. A process of manufacturing a negative electrode material for a nonaqueous electrolyte secondary battery as claimed in Claim 5, further including a step of subjecting the alloy to heat treatment at a temperature at least 10°C below the solidus temperature of the Si-containing soil oducino or intermetalitic compound.
- 10 6. A process for manufacturing a negative electrode material for a nonequeous electrolyte secondary battery, which is made from aboy particles of a structure comprising one or nore Si phase gains and a phase of an Si-containing solid solution or intermetallic compound at least partially enveloping the Si phase grains, characterized by comprising a step of forming an archering layer of a material which contains an element capable of forming a solid solution or an intermetallic compound with Si, on the surface of a powder of metallic Si or an altip having an Si phase, and step of subjecting the powder having the achering layer to heat treatment at a temperature at least 10°C below the solidus temperature of the solid solution or the intermetalic compound to convert the material forming the
 - A process of manufacturing a negative electrode material for a nonaqueous electrolyte secondary battery as claimed in Claim 6, wherein the adhering layer is formed by a plating method or a mechanical alloying method.

adhering layer to form an Si-containing solid solution or intermetallic compound.

- A process of manufacturing a negative electrode material for a nonequeous electrolyte secondary battery as claimed in Claim 3, wherein the negative electrode material which is manufactured condains at least 5 w/% and at most 99 w/% of Si phase grains, and the average particle diameter of the alloy particles is at least 0.1 μm and at most 50 μm.
- 9. A process of manufacturing a negative electrode material for a ronaqueous electrolyte secondary battery as claimed in Colim 6, wherein the negative electrode material with its menufactured contains at least 5 w/4x and at most 99 w/% of Si phase grains, and the average particle diameter of the alloy particles is at least 0.1 μm and at most 50 μm.
- 10. A process of manufacturing a negative electrode material for a nonaqueous electrolyte secondary battery as claimed in Claim? a, wherein the S-containing sold solution or intermediallic compound is made from SI and at least one element selected from the group consisting of Group 2A elements, transition elements, Group 3B elements, and Group 4B elements of the fina SI from the long form periodic table.
- 11. A process of manufacturing a negative electrode material for a ronaqueous electrolyte secondary battery as claimed in Claim 6, wherein the S-containing sold solution or intermedialic compound is made from SI and at least one element selected from the group consisting of Group 2A elements, transition elements, Group 3B elements, and Group 4B elements other than SI from the long form periodic table.
- 12. A process of manufacturing a negative electrode for a nonsqueous electrodyte secondary battery, characterized by athering a powder of matellia Si or of an alloy containing an Si phase on an egative electrode substrate to form a powder layer on the substrate, then plating the powder layer with a material comprising an element capable of forming a solid solidution or intermetalitic compound with St, and threatter performing heat treatment at a temperature at least DPC below the solidus temperature of the solid solidun or intermetallic compound so as to convert the plating to form an Si-containing solid solution or intermetallic compound.
- 13. A process of manufacturing a negative electrode for a nonaqueous electrolyte secondary battery as claimed in Claim 12, wherein the Si-containing solid solution or intermetallic compound is made from Si and at least one element selected from the group consisting of Group 2A elements, transition elements, Group 3B elements, and Group 4B elements other than Si from the long form periodic table.
- 14. A nonaqueous electrolyte secondary battery equipped with a nonaqueous electrolyte and positive and negative electrodes with can reversibly occlude and release lithium, characterized in that the negative electrode includes the negative electrode material of Claim.
- 15. A nonaqueous electrolyte secondary battery equipped with a nonaqueous electrolyte and positive and negative

electrodes which can reversibly occlude and release lithium, characterized in that the negative electrode is a negative electrode containing a negative electrode material manufactured by the process of Claim 3.

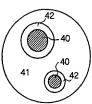
- 16. A nonaqueous electrolyte secondary battery equipped with a nonaqueous electrolyte and positive and negative electrodes which can reversibly collude and release lithium, characterized in that the negative electrode is a negative electrode material manufactured by the process of Claim 6.
- 17. A nonaqueous electrolyte secondary battery equipped with a nonaqueous electrolyte and positive and negative electrodes which can reversibly octubed and release lithium, characterized in that the negative electrode is a negative electrode in an advantage of the process of Claim 12.
 - 18. A nonaqueous electrolyte secondary battery as claimed in Claim 14, wherein the negative electrode contains at least 5 w/% and at most 80 w/% of a carbon material with respect to the negative electrode material.
- 15 19. A nonaqueous electrolyte secondary battery as claimed in Claim 14, wherein the positive electrode comprises a compound of a lithium containing transition metal compound as an active substance, and the nonaqueous electrolyte is a solution of a lithium sat dissolved in a carbonate seter-type organic solvent.

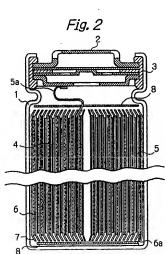
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INTERNATIONAL SEARCH REPORT International application No. PCT/JP99/04775 A. CLASSIFICATION OF SUBJECT MATTER. H01M4/02, H01M4/38, H01M10/40, B22F9/08, B22F9/10 According to International Patent Classification (IPC) or to both national classification and IPC B. FIELDS SEARCHED Minimum documentation searched (classification system followed by classification symbols) Int. Cl² H01M4/02, H01M4/38, H01M10/40, B22F9/08, B22F9/10 mentation tearched other than minimum documentation to the extent that such documents are included in the fields searched July Shinan Koho 1926-1996 Toroku Jibanyo Shinan Koho 1944-1995 Kokai Jitsuyo Shinan Koho 1971-1999 Jitsuyo Shinan Toroku Koh 1996-1995 Toroku Jitsuyo Shinan Koho 1994-1999 Jitsuyo Shinan Toroku Koho 1996-1999 Electronic data base consulted during the international search (name of data base and, where practicable, search terms used) Dialog-4PI/J[file352], Dialog-PCI(file342) JOIS(file010.011) C. DOCUMENTS CONSIDERED TO BE RELEVANT Category* Citation of document, with indication, where appropriate, of the relevant passages Relevant to claim No. JP, 11-176470, A (HITACHI MAXELL, LTD.), 1-4.8.10.14. 02 July, 1999 (02.07.99), Claim 1; Par. Nos. [0015] -[0016],[0020]-[0023], [0029]-[0031] (Pamily: none) 15,18,19 EX JP, 11-86853, A (Hitachi, Ltd.), 1-4,8,10,14, 30 March, 1999 (30.03.99), Claims 1 to 3; Par. Nos. [0010]-[0013], [0016], [0018], 15,18,19 [0021] (Family: none) BX JP, 11-214004, A (Matsushita Blectric Industrial Co., 1-4,8,10,14, 15,18,19 Ltd.), 06 August, 1999 (06.08.99), Claims 1, 4, 8-11; Par. Nos. [0016]-[0021],[0029] ВX JP, 11-242954, A (CANON INC.), 1,2 07 September, 1999 (07.09.99), Claims 1, 8, 12, 15-18, 45, 55-57, 59-62, 90; Par. Nos. [0040] - [0042] , [0044] - [0048] . & SP, 915067, A & CA, 225280, A Further documents are listed in the continuation of Box C. See patent family annex. Special categories of cited documents: 'A.' document defining the general state of the set which is not considered to be of particular episosom 'E' cut'ar document but published on or seller the international filling later document published after the intermational filling date or priority date and not in conflict with the application but cited to understand the principle or thoop underlying the invention document of particular relevance; the chainsof invention consort be considered nevel or cannot be considered to involve an inventive and involve an inventive cannot be considered to involve an inventive "X" document of particular información the claimod invention cannot be considered norm of or cannot be considered to invention cannot be considered norm of or cannot be considered to invention an invention cannot be document oi takon alono "Y" document of particular trainventión the claimed invention cannot be considered to invention as inventions the claimed invention cannot be contributed with one or merce della esta dichocurrent, su, cub combinado with one or merce della esta dichocurrent su, such a combinado to being obvinces as a person altitled in the act "de" document member of the serve parcia finally and contributed to the contributed to t "U" document which may throw doubts on priority claim(s) or which is nited to establish the publication date of another citation or other special reason (as specified) "O" document referring to so exist disclosure, use, estibition or other "P" means document published prior to the inscensional filing dece but later than the priority date claimed Date of the social completion of the international search 29 NOVember, 1999 (29.11.99) Date of mailing of the international search report 07 December, 1999 (07.12.99) Name and mailing address of the ISA/ Authorized officer Japanese Patent Office Telephone No.

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International application No. PCT/JP99/04775

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